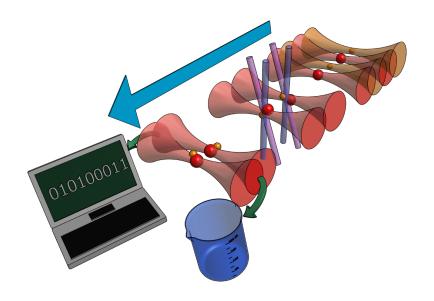
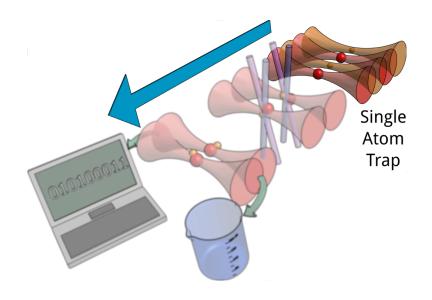
Raman sideband cooling of single sodium atom to 3D ground state

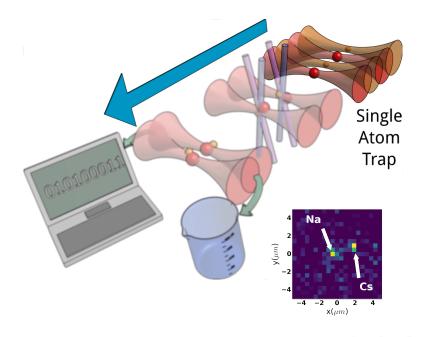
Yichao Yu

Ni Group/Harvard

April 19, 2017



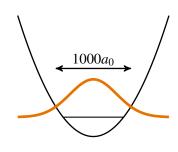




Wave function size

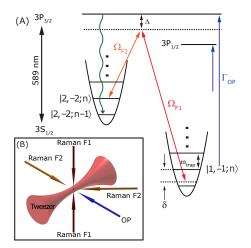


Molecule

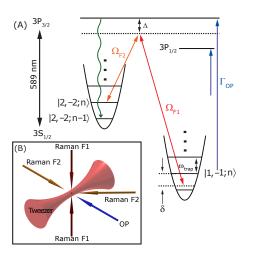


Atom

Raman sideband cooling of Sodium



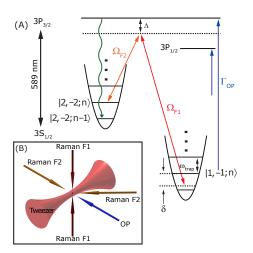
Raman sideband cooling of Sodium



Difficulties

- High initial temperature $(40\mu K)$
- High recoil heating

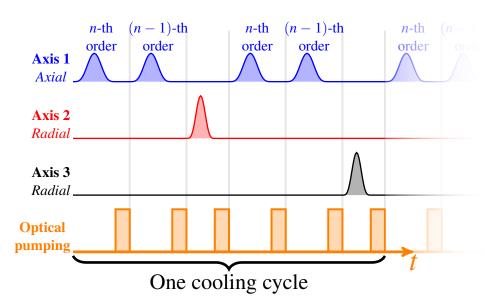
Raman sideband cooling of Sodium

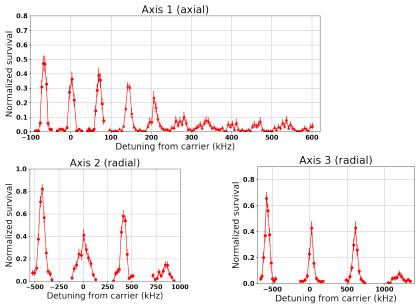


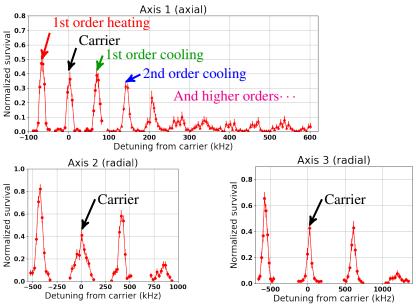
Difficulties

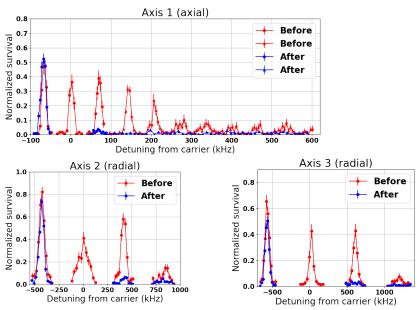
- High initial temperature $(40\mu K)$
- High recoil heating

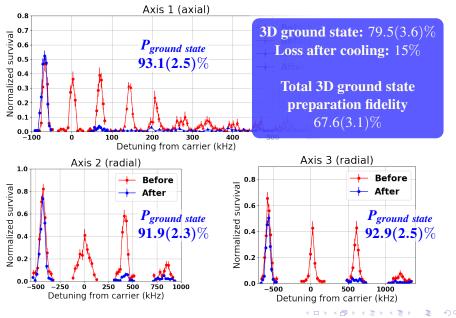
Cooling sequence



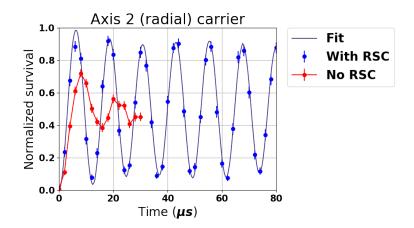






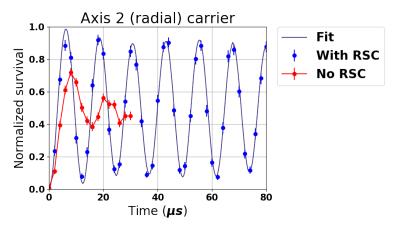


Rabi flopping (radial)



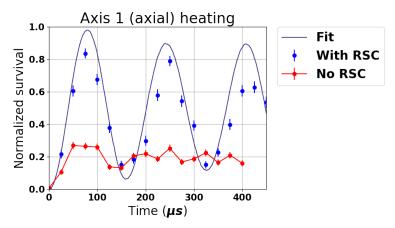
7 / 13

Rabi flopping (radial)



Good agreement between spectrum and Rabi flopping data.

Rabi flopping (axial)



Decoherence caused by magnetic field fluctuation.

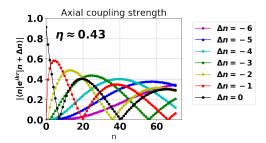
Conclusion

67.6(3.1)% ground state preparation fidelity (79.5(3.6)% without loss)

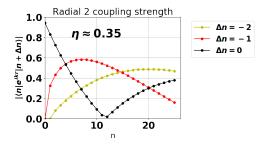
Improvements

- Reduce off-resonance scattering from Raman beams
- Reduce magnetic field fluctuation
- Reduce loss during cooling

Axial matrix element



Radial 2 matrix element



Radial 3 matrix element

